

Title: ELECTRODE, METHOD FOR
MANUFACTURING
THE SAME AND SEMICONDUCTOR
DEVICE USING THE SAME
Inventors: Tatsuo NAKAYAMA, et al.
Atty. Dkt. No. 040373-0381

Fig. 1

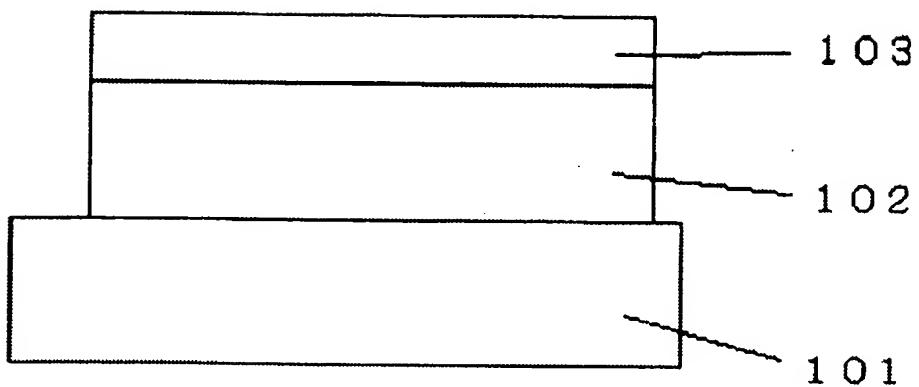


Fig. 2

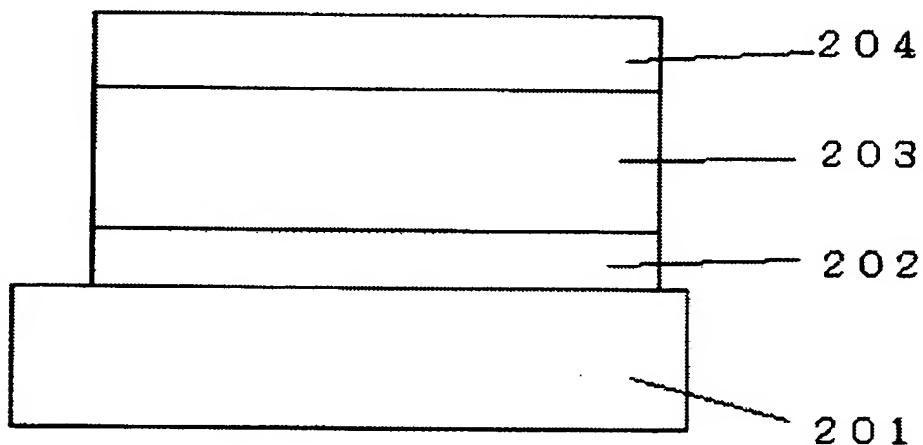
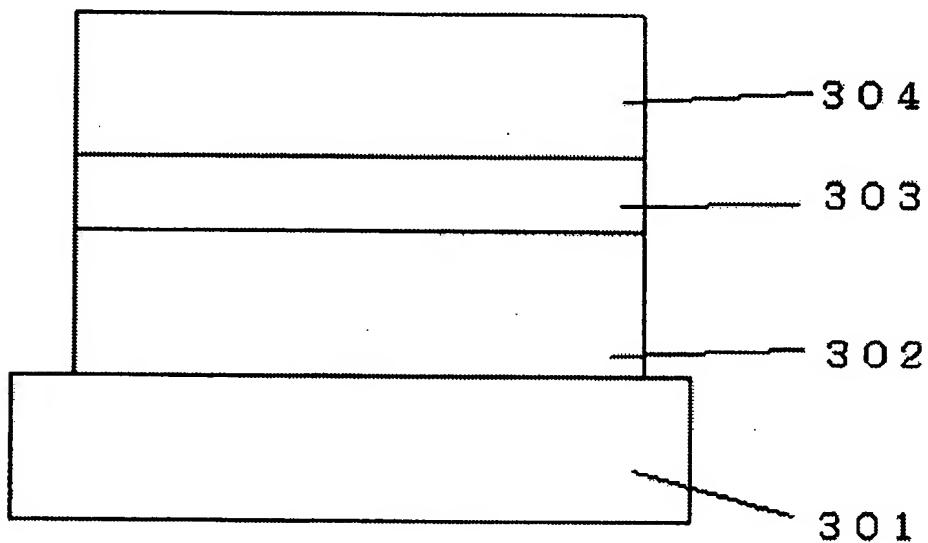


Fig. 3



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Fig. 4

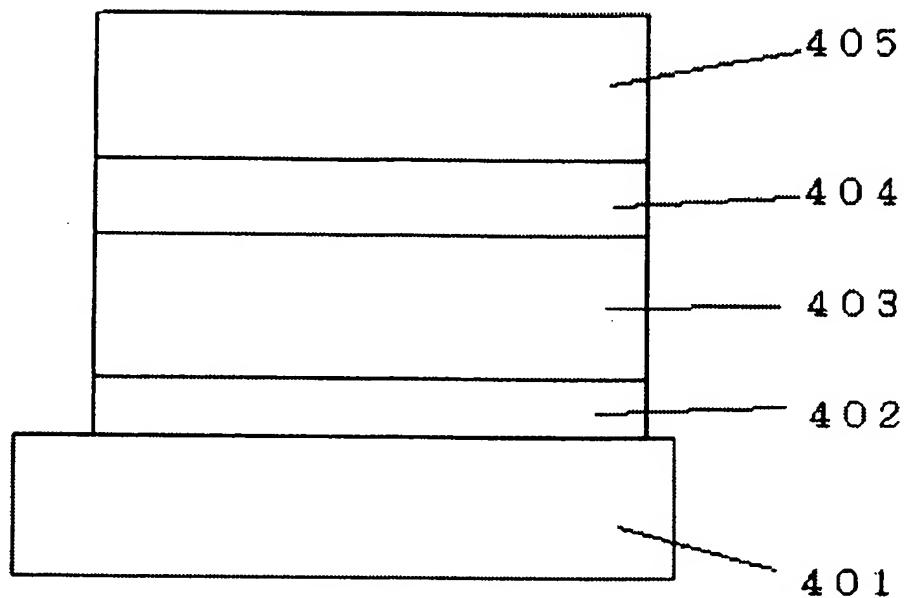
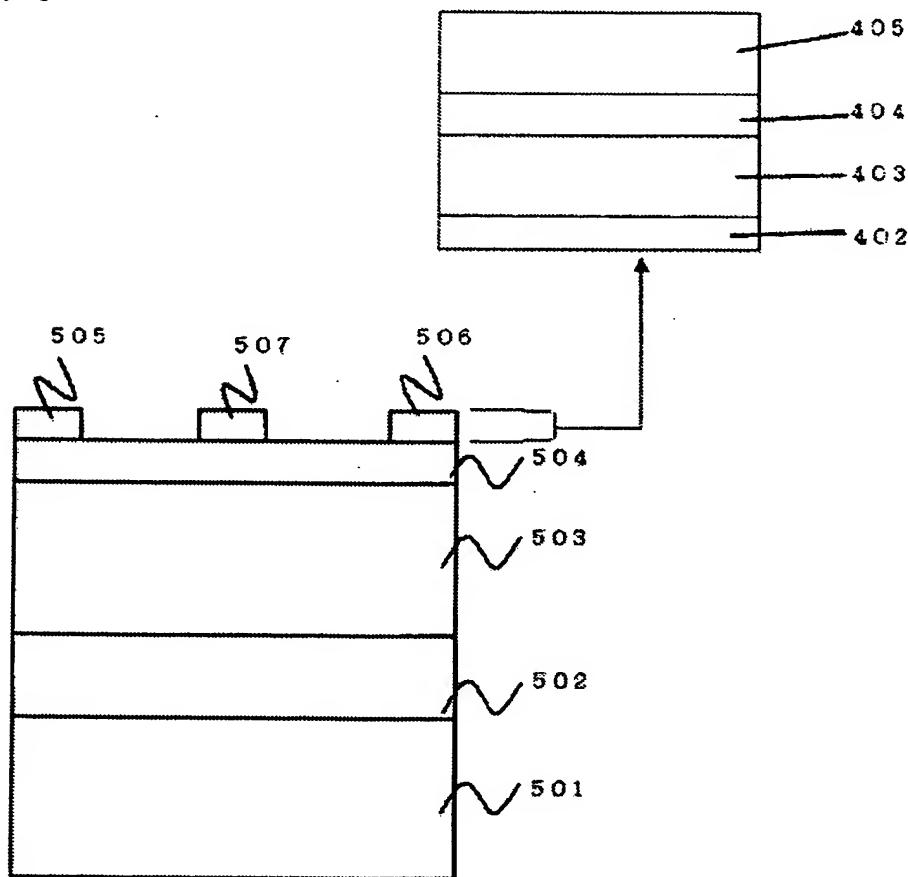
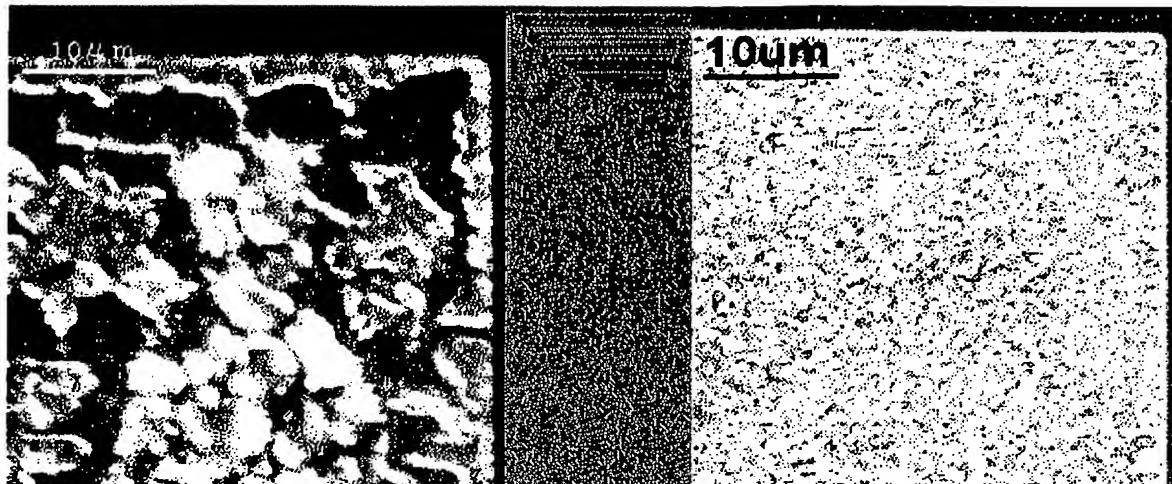


Fig. 5



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Fig. 6



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Fig. 7

Fe-Al Phase Diagram

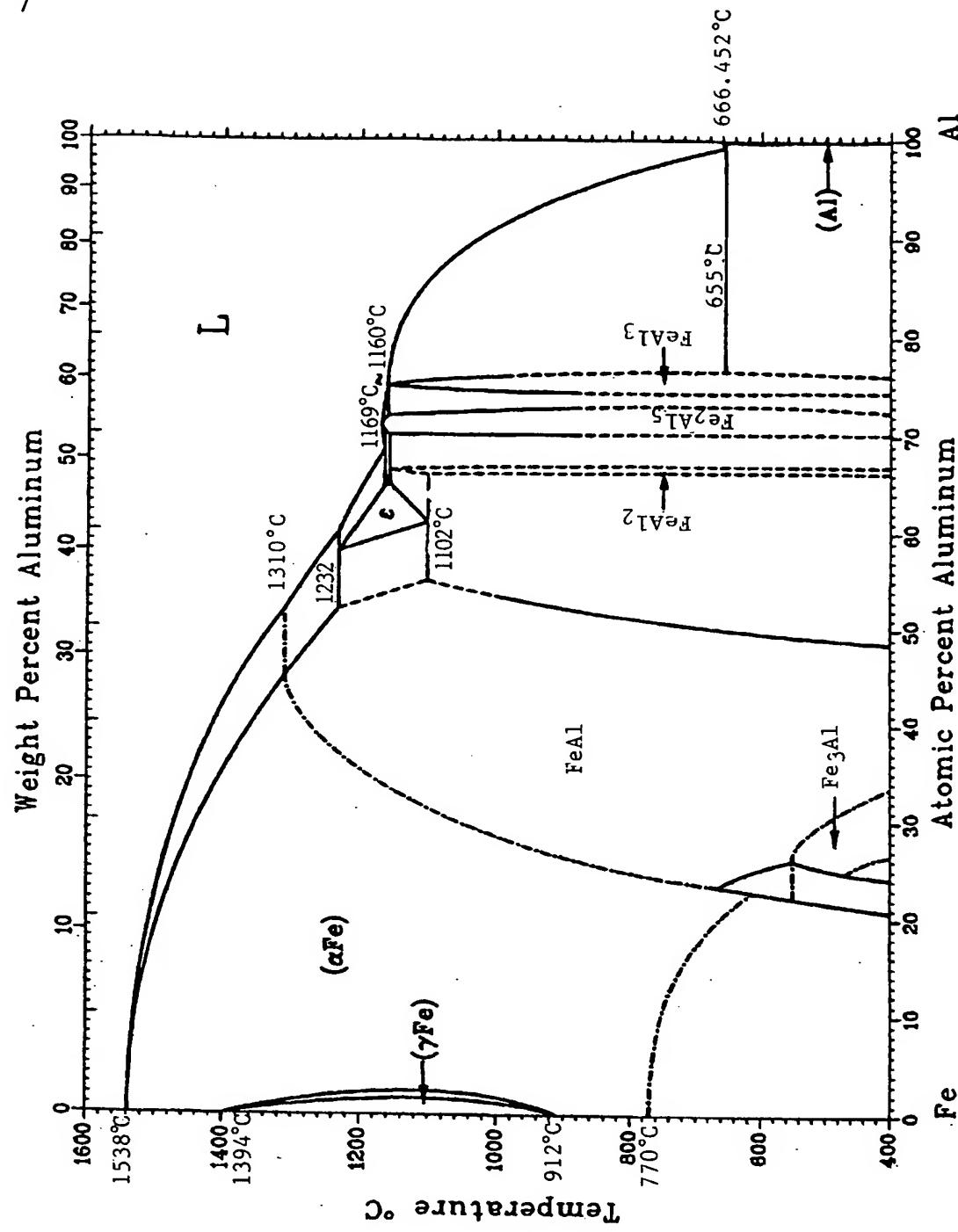
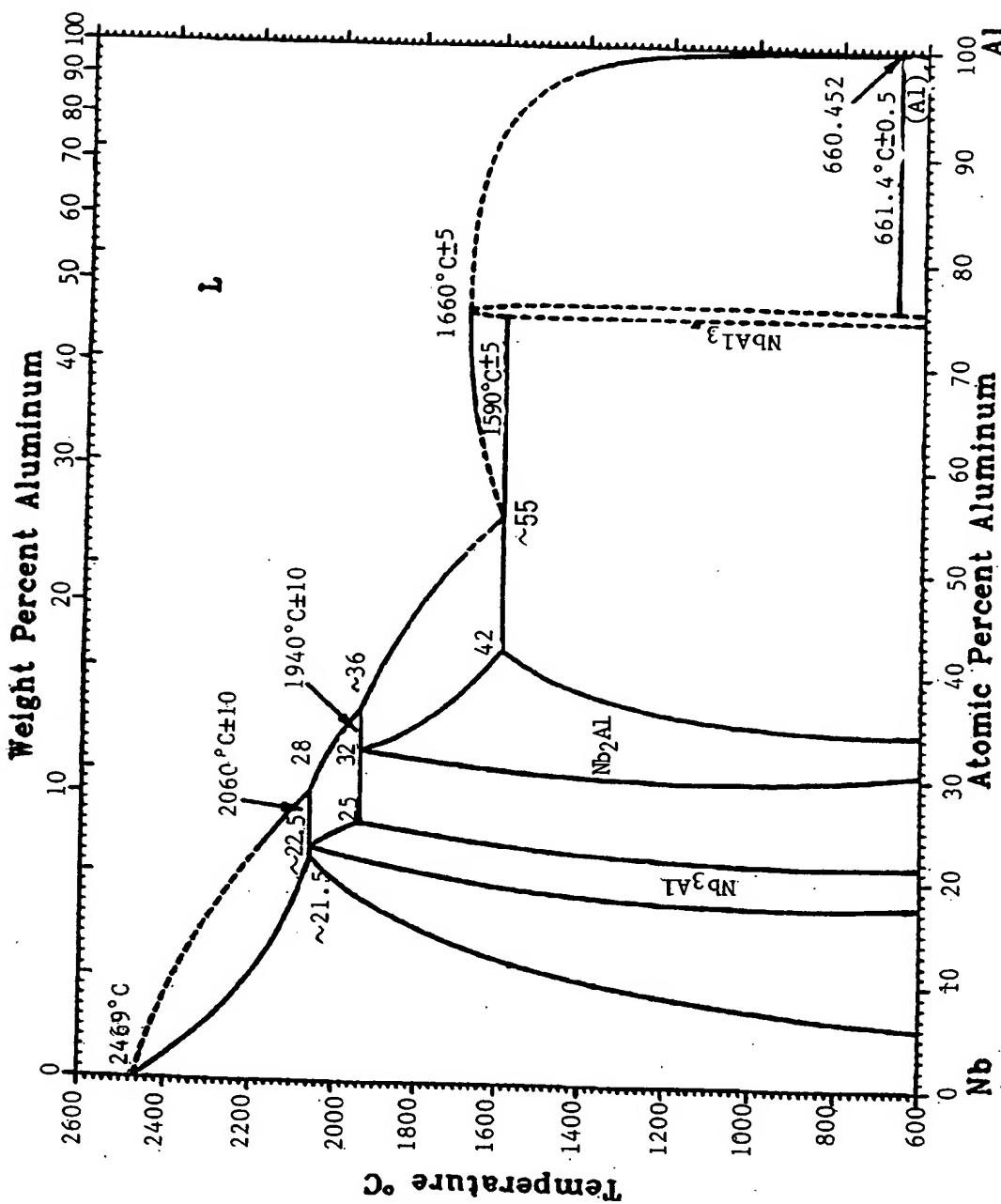


Fig. 8

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Nb-Al Phase Diagram



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Fig. 9

Al-Mo Phase Diagram

